## NSN 5961-01-107-5756

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-107-5756 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 collector to emitter voltage/static/base open and 600.0 collector to base voltage/static/emitter open and 10.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads gold **Precious Material:** Gold

### **Test Data Document:**

09344-pc71597 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

1 case and 2 uninsulated wire lead

## Shelf Life:

N/a

#### **Unit Of Measure:**

# NSN 5961-01-107-5756

Transistor - Page 2 of 2



_		••	• •				
וו	em	ш	112	rız	211	n	٠.

No

Fiig:

A110a0